1.1GHz Low Power Dual Modulus Prescaler With On-Chip Output Termination

The MC12022TSA can be used with CMOS synthesizers requiring positive edges to trigger internal counters such as Motorola's MC145XXX series in a PLL to provide tuning signals up to 1.1GHz in programmable frequency steps. This device is a reduced current drain version of the MC12022A/B with the addition of on–chip output termination.

The MC12022TSB can be used with CMOS synthesizers requiring negative edges to trigger internal counters.

A Divide Ratio Control (SW) permits selection of a 64/65 or 128/129 divide ratio as desired.

The Modulus Control (MC) selects the proper divide number after SW has been biased to select the desired divide ratio.

- 1.1 GHz Toggle Frequency
- Supply Voltage of 4.5 to 5.5V
- Low-Power 4.0mA Typical
- Operating Temperature Range of –40 to +85°C
- Short Setup Time (tset) 16ns Maximum @ 1.1GHz
- Modulus Control Input Level Is Compatible With Standard CMOS and TTL
- · Output Load Resistor on Die

FUNCTIONAL TABLE

sw	МС	Divide Ratio
Н	Н	64
Н	L	65
L	Н	128
L	L	129

Note: SW: $H = V_{CC}$, L = Open $MC: H = 2.0 \text{ V to } V_{CC}$, L = GN

MC: H = 2.0 V to V_{CC} , L = GND to 0.8 V

DESIGN GUIDE

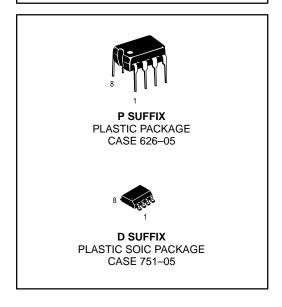
Criteria	Value	Unit
Internal Gate Count*	67	ea
Internal Gate Propagation Delay	200	ps
Internal Gate Power Dissipation	0.75	mW
Speed Power Product	0.15	pJ

^{*} Equivalent to a two-input NAND gate

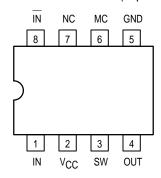
MC12022TSA MC12022TSB

MECL PLL COMPONENTS

÷64/65, ÷128/129 DUAL MODULUS PRESCALER



Pinout: 8-Lead Plastic (Top View)



MAXIMUM RATINGS

1/96

Symbol	Characteristic	Range	Unit
VCC	Power Supply Voltage, Pin 2	-0.5 to + 7.0	Vdc
T _A	Operating Temperature Range	-40 to + 85	°C
T _{stg}	Storage Temperature Range	-65 to + 150	°C

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ELECTRICAL CHARACTERISTICS ($V_{CC} = 4.5 \text{ to } 5.5V$; $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$)

Symbol	Characteristic	Min	Тур	Max	Unit
f _t	Toggle Frequency (Sine Wave Input)	0.1	1.4	1.1	GHz
^I CC	Supply Current (Pin 2)		4.6	6.5	mA
V _{IH1}	Modulus Control Input High (MC)	2.0		V _{CC} + 0.5V	V
V _{IL1}	Modulus Control Input Low (MC)			0.8	V
V _{IH2}	Divide Ratio Control Input High (SW)	V _{CC} – 0.5V	VCC	V _{CC} + 0.5V	Vdc
V _{IL2}	Divide Ratio Control Input Low (SW)	Open	Open	Open	
V _{out}	Output Voltage Swing (C _L = 8pF)	1.0	1.4		V _{p-p}
t _{set}	Modulus Setup Time MC to Out		11	16	ns
V _{in}	Input Voltage Sensitivity 250–1100 MHz 100–250 MHz	100 400		1500 1500	mVpp

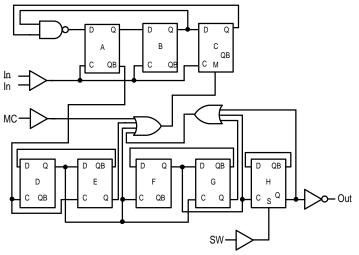
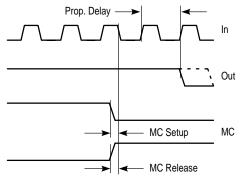
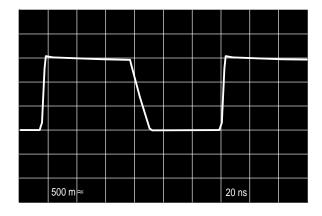


Figure 1. Logic Diagram (MC12022TSA)

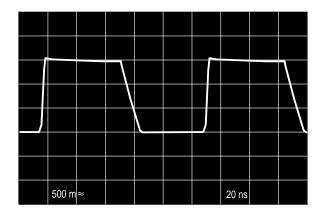


Modulus setup time MC to out is the MC setup or MC release plus the prop delay.

Figure 2. Modulus Setup Time



(÷64, 500MHz Input Frequency, V_{CC} = 5.0V, T_{A} = 25°C, Output Loaded)



(÷128, 1.1GHz Input Frequency, V_{CC} = 5.0V, T_A = 25°C, Output Loaded)

Figure 3. Typical Output Waveforms

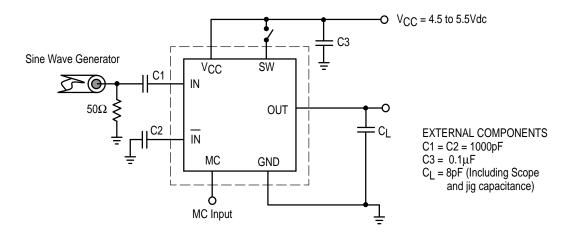


Figure 4. AC Test Circuit

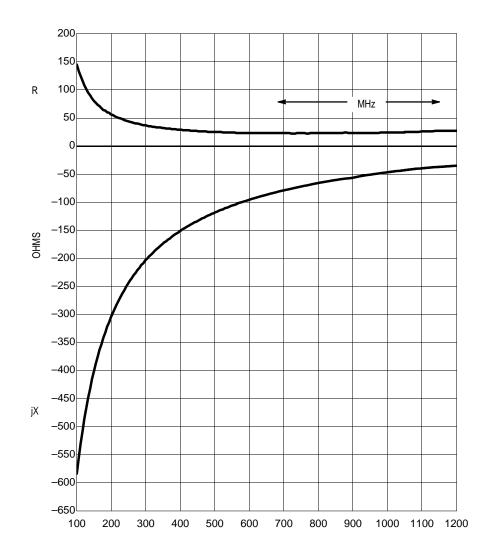
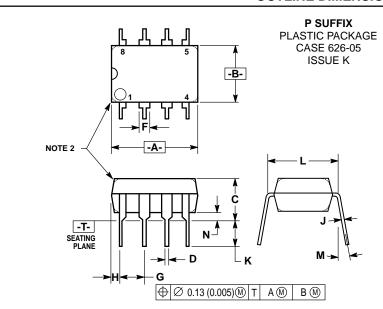


Figure 5. Typical Input Impedance versus Input Frequency

OUTLINE DIMENSIONS

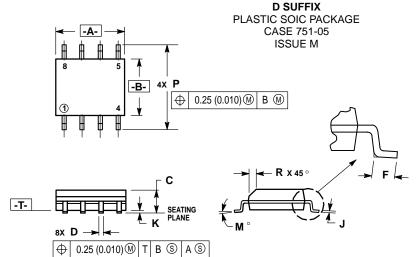


NOTES:

- DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
- 2. PACKAGE CONTOUR OPTIONAL (ROUND OR
- SQUARE CORNERS).

 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.

	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.40	10.16	0.370	0.400	
В	6.10	6.60	0.240	0.260	
С	3.94	4.45	0.155	0.175	
D	0.38	0.51	0.015	0.020	
F	1.02	1.78	0.040	0.070	
G	2.54 BSC		0.100 BSC		
Н	0.76	1.27	0.030	0.050	
J	0.20	0.30	0.008	0.012	
K	2.92	3.43	0.115	0.135	
L	7.62 BSC		0.300 BSC		
М	_	10°	_	10°	
N	0.76	1.01	0.030	0.040	



NOTES:

- DIMENSIONING AND TOLERANCING PER
 ANSI Y14.5M. 1982.
- CONTROLLING DIMENSION: MILLIMETER
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS BIGUES				
	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.196	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27 BSC		0.050 BSC		
J	0.18	0.25	0.007	0.009	
K	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

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